

isc Silicon PNP Power Transistor

DESCRIPTION

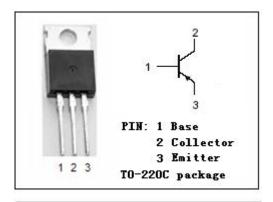
- · Collector-Emitter Breakdown Voltage-
 - : $V_{(BR)CEO}$ = -80V(Min)
- Good Linearity of h_{FE}
- · Low Collector Saturation Voltage
 - : $V_{CE(sat)}$ = -0.5 $V(Max)@I_C$ = -4A
- Complement to Type 2SD961
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

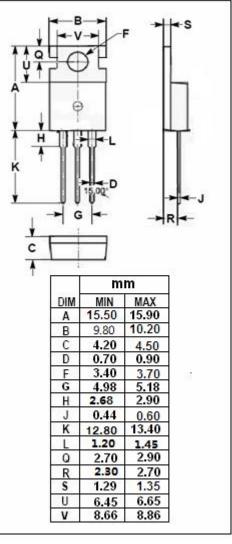
APPLICATIONS

· Designed for power switching applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL | PARAMETER | VALUE | UNIT | |
|------------------|---|-------|--------------|--|
| V _{CBO} | Collector-Base Voltage | -130 | V | |
| VCEO | Collector-Emitter Voltage | -80 | V | |
| V _{EBO} | Emitter-Base Voltage | -7 | V | |
| Ic | Collector Current-Continuous | -5 | А | |
| I _{CM} | Collector Current-Peak | -10 | А | |
| Pc | Collector Power Dissipation @ T _C =25℃ | | W | |
| Тл | Junction Temperature 150 | | $^{\circ}$ C | |
| T _{stg} | T _{stg} Storage Temperature Range | | $^{\circ}$ C | |







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2SB869

ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | MAX | UNIT | | |
|----------------------|--------------------------------------|---|-----|------|------|------|--|--|
| V _{(BR)CEO} | Collector-Emitter Breakdown Voltage | I _C = -10mA; I _B = 0 | -80 | | | V | | |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = -4A; I _B = -0.2A | | | -0.5 | V | | |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | I _C = -4A; I _B = -0.2A | | | -1.5 | V | | |
| Ісво | Collector Cutoff Current | V _{CB} = -100V; I _E = 0 | | | -10 | μА | | |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = -5V; I _C = 0 | | | -50 | μА | | |
| h _{FE-1} | DC Current Gain | I _C = -0.1A; V _{CE} = -2V | 45 | | | | | |
| h _{FE-2} | DC Current Gain | I _C = -2A; V _{CE} = -2V | 60 | | 260 | | | |

♦ h_{FE-2} Classifications

| R | Q | Р |
|--------|--------|---------|
| 60-120 | 90-180 | 130-260 |

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